

# 600V 8A Fast Recovery Diode

### **Description**

FRED from Lonten utilizes advanced processing techniques to achieve ultra-fast recovery times and higher forward current. Its soft recovery characteristics and high reliability suit for wide industrial applications.

#### **Features**

- ◆ Low power loss, high efficiency
- High reliability
- ♦ RoHS product

### **Applications**

- ◆ Active power factor correction
- Switch power supply
- ◆ PFC

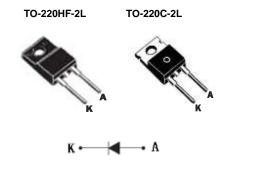
## **Product Summary**

600V

A8

**FRED** 

### **TO-220 Pin Configuration**



### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Parameter	Symbol	Value	Unit
Maximum D.C. Reverse Voltage	$V_R$	600	V
Maximum Repetitive Reverse Voltage	$V_{RRM}$	600	V
Average Forward Current( Tc = 110°C)	I <sub>F(AV)</sub>	8	А
RMS Forward Current( Tc = 110 °C)	I <sub>F(RMS)</sub>	21	Α
Non-Repetitive Surge Forward Current(TJ =	I <sub>FSM</sub>	80	A
45℃,t=10ms,50Hz,Sine)			
Power Dissipation	P <sub>D</sub>	83	W
Junction Temperature Range	TJ	-50 to +150	°C
Storage Temperature Range	T <sub>STG</sub>	-50 to +150	°C
Module-to-Sink(Recommended M3)	Torque	1.1	Nm
	Weight	2.1	g

### Thermal Characteristics TO-220HF2L

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R <sub>θJC</sub>	3.5	°C/W

### Thermal Characteristics TO-220C2L

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	R <sub>eJC</sub>	2.2	°C/W

# LDC60U08W4\LDD60U08W4

## **Package Marking and Ordering Information**

Device	Device Package	Marking
LDD60U08W4	TO-220HF-2L	LDD60U08W4
LDC60U08W4	TO-220C-2L	LDC60U08W4

## **Electrical Characteristics** T<sub>J</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I <sub>RM</sub> Reverse Leakage Current	Barrage Landson Comment	V <sub>R</sub> =600V			50	uA
	Reverse Leakage Current	V <sub>R</sub> =600V, T <sub>J</sub> =125°C			200	uA
V <sub>F</sub> Forward Voltage	Famurad Voltage	I <sub>F</sub> =8A		1.8	2.4	V
	Forward voltage	I <sub>F</sub> =8A, T <sub>J</sub> =125℃		1.5	2.1	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> =1A, V <sub>R</sub> =30V,		19	30	ns
		di <sub>F</sub> /d <sub>t</sub> =-200A/us				

## **Electrical Characteristics Diagrams**

Figure 1. I<sub>F</sub> vs V<sub>F</sub>

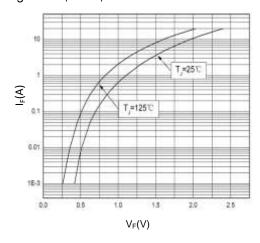


Figure 2.  $I_R$  vs  $V_R$ 

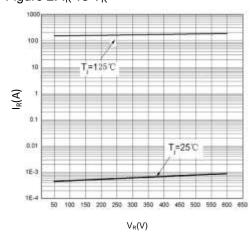
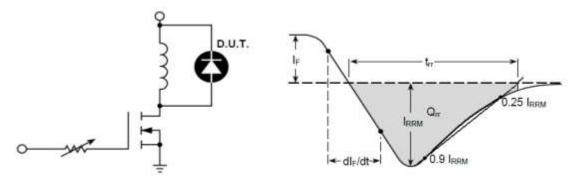


Figure 3. Diode Reverse Recovery Test Circuit and Waveform

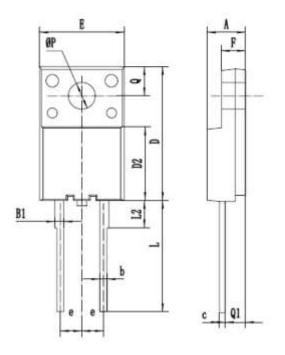


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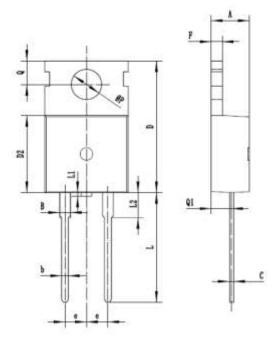
Figure 4. Package Outline Dimensions in Millimeters

### Mechanical Dimensions for TO-220HF-2L



Symbol	MIN	MAX	
Α	4.0	5.0	
B1	0.87	1.27	
b	0.72	0.92	
С	0.5	0.7	
D	15.0	16.5	
D2	7.8	9.4	
Е	9.62	10.62	
е	2.54(TYP.)		
F	2.3	3.3	
L	13.0	14.0	
L2	3.1	3.5	
ΦР	3.0	3.4	
Q	3.15	3.55	
Q1	2.2	2.5	

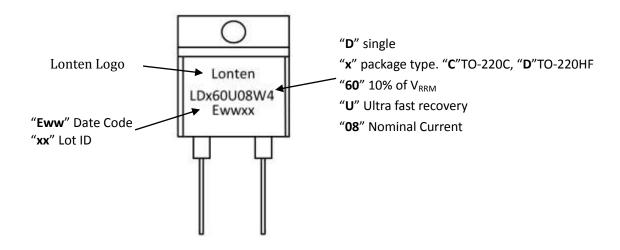
#### **Mechanical Dimensions for TO-220C-2L**



Symbol	MIN	MAX
Α	4.30	4.70
В	1.22	1.40
b	0.70	0.95
С	0.40	0.65
D	15.20	16.20
D2	9.00	9.40
Е	9.70	10.10
е	2.39	2.69
F	1.25	1.40
L	12.60	13.60
L1	0.20	0.50
L2	2.80	3.20
Q	2.60	3.00
Q1	2.20	2.60
Р	3.5	3.80

# LDC60U08W4\LDD60U08W4

### **Marking Information**



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